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## **COPPER SULFIDES THIN FILMS WITH CONTROLLED PROPERTIES FOR PHOTOVOLTAIC CELLS**

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### **Abstract**

Films of Cu<sub>x</sub>S with 430-700 nm thickness were deposited by robotic spray pyrolysis technique, at  $T = 300^\circ\text{C}$ , using 90 spraying sequences, from water:ethanol:glycerol = 7:2:1 (in volumes) solutions with a molar ratio Cu:S = 1:2.5-3.5. Relative dense, homogenous and uniform films of Cu<sub>x</sub>S ( $x = 1.8-2$ ), with  $E_g = 1.97-2.49$  eV and exhibiting electric resistance behavior were obtained. The as-deposited films were annealed in air or in sulfur atmosphere, at  $300^\circ\text{C}$ , for one hour. Dense and uniform films, containing Cu<sub>2</sub>S crystalline phase, with  $E_g = 2.16$  eV and *p*-type semiconductor electrical behavior, were obtained by annealing in air of films deposited from precursors' solutions with Cu:S = 1:3 at Cu<sup>2+</sup> concentration of 3.5 mol/L.

**Key words:** copper sulfides, photovoltaic cells, robotic spray pyrolysis, thin films

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